

## BD175/177/179

# Medium Power Linear and Switching Applications

· Complement to BD 176/178/180 respectively



## **NPN Epitaxial Silicon Transistor**

## Absolute Maximum Ratings T<sub>C</sub>=25°C unless otherwise noted

Symbol	Paramet	Value	Units	
V <sub>CBO</sub>	*Collector-Base Voltage	: BD175	45	V
		: BD177	60	V
		: BD179	80	V
V <sub>CEO</sub>	Collector-Emitter Voltage	: BD175	45	V
		: BD177	60	V
		: BD179	80	V
V <sub>EBO</sub>	Emitter-Base Voltage		5	V
I <sub>C</sub>	Collector Current (DC)		3	А
I <sub>CP</sub>	*Collector Current (Pulse)		7	А
Pc	Collector Dissipation (T <sub>C</sub> =25°C)		30	W
T <sub>J</sub>	Junction Temperature		150	°C
T <sub>STG</sub>	Storage Temperature		- 65 ~ 150	°C

### Electrical Characteristics T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter		Test Condition	Min.	Тур.	Max.	Units
V <sub>CEO</sub> (sus)	* Collector-Emitter Sustaining	Voltage					
		: BD175	I <sub>C</sub> = 100mA, I <sub>B</sub> = 0	45			V
		: BD177		60			V
		: BD179		80			V
I <sub>CBO</sub>	Collector Cut-off Current	: BD175	V <sub>CB</sub> = 45V, I <sub>E</sub> = 0			100	αA
		: BD177	$V_{CB} = 60V, I_{E} = 0$			100	αA
		: BD179	$V_{CB} = 80V, I_{E} = 0$			100	œΑ
I <sub>EBO</sub>	Emitter Cut-off Current		V <sub>EB</sub> = 5V, I <sub>C</sub> = 0			1	mΑ
h <sub>FE1</sub>	* DC Current Gain		V <sub>CE</sub> = 2V, I <sub>C</sub> = 150mA	40		250	
h <sub>FE2</sub>			$V_{CE} = 2V, I_{C} = 1A$	15			
V <sub>CE</sub> (sat)	* Collector-Emitter Saturation	Voltage	I <sub>C</sub> = 1A, I <sub>B</sub> = 0.1A			0.8	V
V <sub>BE</sub> (on)	* Base-Emitter On Voltage		V <sub>CE</sub> = 2V, I <sub>C</sub> = 1A			1.3	V
fт	Current Gain Bandwidth Prod	duct	V <sub>CF</sub> = 10V, I <sub>C</sub> = 250mA	3			MHz

## **h**<sub>FE</sub> Classificntion

Classification	6	10	16	
h <sub>FE1</sub>	40 ~ 100	63 ~ 160	100 ~ 250	
* Classification 16: Only BD175				

## **Typical Characteristics**

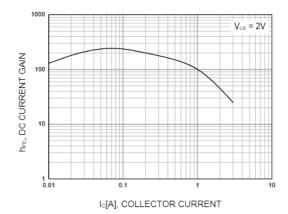


Figure 1. DC current Gain

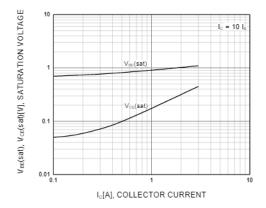


Figure 2. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

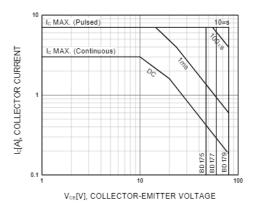


Figure 3. Safe Operating Area

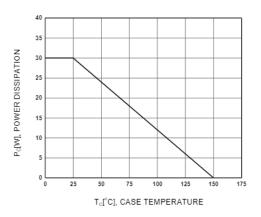
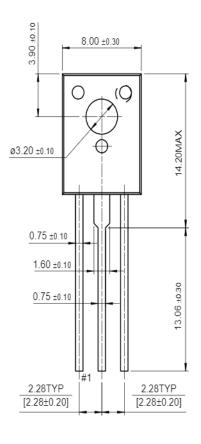
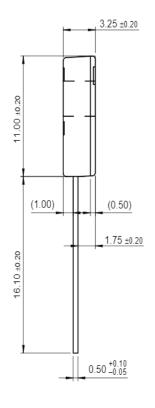


Figure 4. Power Derating

## **Package Demensions**

TO-126







Dimensions in Millimeters

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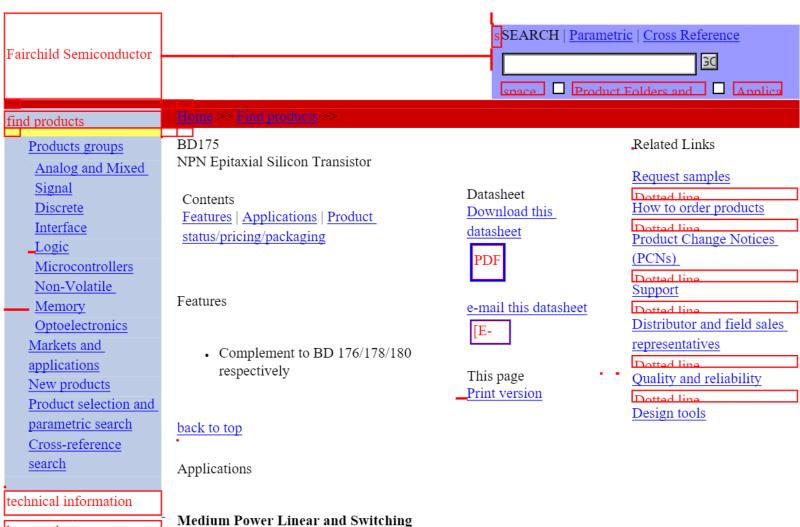
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Product status/pricing/packaging

Product	Product status	Pricing*	Package type	Leads	Packing method
BD17516STU	Full Production	\$0.18	<u>TO-126</u>	3	RAIL
BD1756STU	Full Production	\$0.18	<u>TO-126</u>	3	RAIL
BD17510STU	Full Production	\$0.18	<u>TO-126</u>	3	RAIL

<sup>\* 1,000</sup> piece Budgetary Pricing

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